

Quantum transport in quantum dot cascade structures

<u>Nenad Vukmirović</u>, Dragan Indjin, Zoran Ikonić, and Paul Harrison School of Electronic and Electrical Engineering, University of Leeds, Leeds LS2 9JT, United Kingdom

The 9th International Conference on Intersubband Transitions in Quantum Wells, 9-14 September 2007, Ambleside, Cumbria, UK

Introduction



•Electron transport through arrays of closely stacked quantum dots.



The interest comes from several anticipated device applications:

- Solar cells
- Thermoelectric devices
- Quantum cascade lasers

Outline of the talk



Theoretical approach – the formalism of nonequilibrium Green's functions.

Transport through a superlattice consisting of one QD per period

• Electron-phonon resonances

•Simulation of a simple QD quantum cascade structure designed to exhibit gain in the terahertz range.



Theoretical approach – the formalism of nonequilibrium Green's functions

The choice of the theoretical approach



◆Semiclassical models often work relatively well in nanostructures with continuous spectra and are used in simulations of QW based QCLs.

♦Quantum dots

- Discrete electronic spectrum the phase space for relaxation and dephasing processes is significantly reduced.
- Electronic coupling between neighbouring dots the effect of electron tunnelling in closely stacked quantum dots.

An approach taking fully into account coherent effects is therefore necessary.

•Two such formalisms exist in the literature

- The density matrix formalism.
- The formalism of nonequilibrium Green's functions.

A bit of theory (1)

♦Steady-state transport

- ◆The Green's functions (in energy domain) satisfy the following equations
 - The Dyson equation: $\sum_{\alpha} \left[E \delta_{\alpha \gamma} \left(H_{\alpha \gamma} + \Sigma_{\alpha \gamma}^{R}(E) \right) \right] G_{\gamma \beta}^{R}(E) = \delta_{\alpha \beta}$
 - The Keldysh relation: $G_{\alpha\beta}^{<}(E) = \sum_{\mu\beta} G_{\alpha\gamma}^{R}(E) \Sigma_{\gamma\delta}^{<}(E) G_{\delta\beta}^{A}(E)$

•Rough analogy with semiclassical equations: Dyson ~ Schrödinger, Keldysh ~ Boltzmann, $G^{R}(E)$ ~ density of states, $G^{<}(E)$ ~ populations (and coherences), $\Sigma^{<}(E)$ ~ scattering.

•Electronic miniband structure was solved using the 8-band $\mathbf{k} \cdot \mathbf{p}$ model with the effects of strain taken into account

◆The basis of maximally localised Wannier states, well localised to one period of the structure, was then constructed – gives an insight into the carrier transport in real space.

UNIVERSITY OF LEEDS

A bit of the ory (2)

Electron – LO phonon interaction modelled with the Frölich Hamiltonian and taken into account within the self consistent Born approximation

$$\Sigma_{\alpha\beta}^{<}(E) = i \sum_{\gamma\delta,q} M_{\beta\delta}(q)^{*} M_{\alpha\gamma}(q) \frac{1}{2\pi} \int dE' G_{\gamma\delta}^{<}(E-E') D^{<}(E')$$

(and a similar expression for $\Sigma^{R}(E)$)

♦Finite LO phonon lifetime Γ also considered $D^{R}(E) = \frac{1}{E - E_{IO} + i\Gamma} - \frac{1}{E + E_{IO} + i\Gamma}$ (and a similar expression for D[<](E))

◆Electron - acoustic phonon interaction also modelled within the SCBA.

◆Low carrier and doping limit – no e-e interactions, no interactions with impurities, no formation of domains (constant electric field).

Shift-invariance property of a periodic system in a constant el. field used to close the system of equations which was then solved self-consistently.

•Current calculated from
$$I = -\frac{|e|}{L_z \hbar} \sum_{\beta}' \sum_{\alpha} [H_0, z]_{\alpha\beta} \frac{1}{2\pi} \int dE G_{\beta\alpha}^{<}(E)$$



Transport through a superlattice consisting of one QD per period

Current-field characteristics



InAs/GaAs lens-shaped QDs, D=20nm, h=5nm, T=77K.
Transport takes place through QD ground states.



•Calculation for different values of the period of the structure.





The main peak and its doublet structure



◆The density of states has a maximum at the energy of the ground state, as well as at the energy of phonon replica separated by energy larger than E_{LO} (by polaron shift).

The stronger peak of the doublet originates from LO phonon scattering between ground states of neighbouring periods.

The weaker peak of the doublet comes from tunneling to phonon replica.

◆The doublet structure is a transpor signature of polaron effects.



Other peaks

◆For smaller values of the period, the nature of transport at the main peak is the same, however due to broadening the components of the doublet are indistinguishable.

Additional peaks appear

- When potential drop per period V_F is half the LO phonon energy.
- In principle the peaks are present whenever nV_F=mE_{LO}.





Transport through a QD cascade structure

Design of the structure



◆Discrete states in QDs – reduced transition rates – reduced current (compared to QW structures).

♦QD QCLs are therefore expected to have significantly lower operating currents.

♦The design consisting of two QDs per period (A and B, h_A =5nm, h_B =4.5nm, D=20nm, separating barrier 3nm).

•Fast LO phonon depopulation B2 to A1 at the design field, enables population inversion between A2 and B2. $\Lambda 2$



Simulation



◆Field-current characteristic simulated around the design field.

♦Population inversion present in the whole range of fields in the figure.

♦At F=32kV/cm and T=77K
population inversion is 56%,
transition energy 19meV (4.6 THz).



♦Assuming carrier density of 10¹⁰cm⁻²

- The current at F=32kV/cm is J=15A/cm².
- The estimated peak gain is 470cm⁻¹ (assuming FWHM 12%).

◆The region of positive differential resistivity and significant values of gain – stable device operation in this region should be feasible.

Summary



- Theoretical approach the formalism of nonequilibrium Green's functions.
- Transport through a superlattice consisting of one QD per period
 - Doublet structure of the main peak as a signature of polaron effects
- •Simulation of a simple QD quantum cascade structure designed to emit in the terahertz range.
 - Region of positive differential resistivity and significant values of gain, with low operating current.